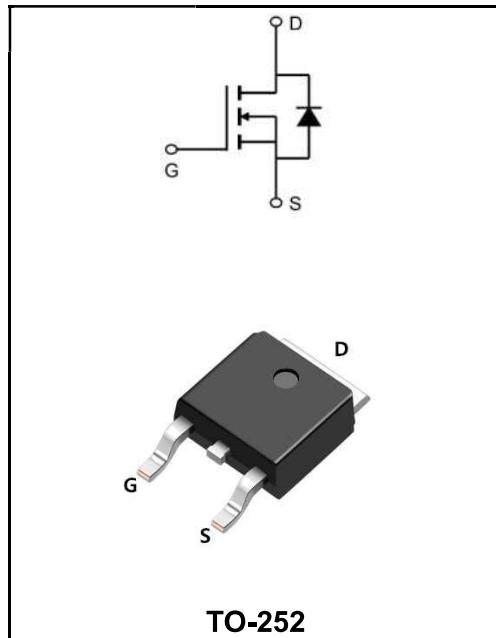


60V N-CHANNEL ENHANCEMENT MODE MOSFET
MAIN CHARACTERISTICS

I_D	70A
V_{DSS}	60V
R_{DSON-typ(@V_{GS}=10V)}	< 10mΩ(Type:8.0 mΩ)


Application

- ◆ Battery protection
- ◆ Load switch
- ◆ Uninterruptible power supply

Product Specification Classification

Part Number	Package	Marking	Pack
YFW70N06AD	TO-252	YFW 70N06AD XXXXX	2500PCS/Tape

Maximum Ratings at T_c=25°C unless otherwise specified

Characteristics	Symbols	Value	Units
Drain-Source Voltage	V _{DS}	60	V
Gate - Source Voltage	V _{GS}	±20	V
Continuous Drain Current, V _{GS} @ 10V ¹ @T _c =25°C	I _D	70	A
Continuous Drain Current, V _{GS} @ 10V ¹ @T _c =100°C	I _D	36	A
Continuous Drain Current, V _{GS} @ 10V ¹ @T _A =25°C	I _D	10.2	A
Continuous Drain Current, V _{GS} @ 10V ¹ @T _A =70°C	I _D	9.5	A
Pulsed Drain Current ²	I _{DM}	100	A
Single Pulse Avalanche Energy ³	E _{AS}	72.2	mJ
Avalanche Current	I _{AS}	38	A
Total Power Dissipation ⁴ @T _c =25°C	P _D	52	W
Total Power Dissipation ⁴ @T _A =25°C	P _D	2	W
Storage Temperature Range	T _{STG}	-55 to +150	°C
Operating and Storage Temperature Range	T _J	-55 to +150	°C
Thermal Resistance Junction-Ambient ¹	R _{θJA}	62	°C/W
Thermal Resistance Junction-Case ¹	R _{θJC}	2.4	°C/W

Maximum Ratings at T_c=25°C unless otherwise specified

Characteristics	Test Condition	Symbols	Min	Typ	Max	Units
Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250μA	BV _{DSS}	60	65	-	V
BVDSS Temperature Coefficient	Reference to 25°C , I _D =1mA	ΔBV _{DSS/ΔTJ}	-	0.052	-	V/°C
Static Drain-Source On-Resistance ²	V _{GS} =10V, I _D =30A	R _{DS(ON)}	-	8.0	10	mΩ
Gate -Threshold Voltage	V _{DS} =V _{GS} , I _D =250μA	V _{GS(th)}	2.0	2.9	4.0	V
V _{GS(th)} Temperature Coefficient		ΔV _{GS(th)}	-	-5.76	-	mV/°C
Drain -Source Leakage Current	V _{DS} =48V , V _{GS} =0V , T _J =25°C	I _{DSS}	-	-	1	μA
	V _{DS} =48V , V _{GS} =0V , T _J =55°C		-	-	5	
Gate-Source Leakage Current	V _{GS} =±20V, V _{DS} =0V	I _{GSS}	-	-	±100	nA
Forward Transconductance	V _{DS} =5V, I _D =30A	g _{FS}	-	42	-	S
Gate Resistance	V _{DS} =0V , V _{GS} =0V , f=1MHz	R _g	-	1.5	-	Ω
Total Gate Charge(4.5V)	V _{DS} =48V V _{GS} =4.5V I _D =15A	Q _g	-	28.7	-	nC
Gate-Source Charge		Q _{gs}	-	10.5	-	
Gate-Drain Charge		Q _{gd}	-	9.9	-	
Turn-on delay time	V _{DD} =30V V _{GS} =10V R _G =3.3Ω I _D =15A	t _{d(on)}	-	10.4	-	ns
Rise Time		T _r	-	9.2	-	
Turn-Off Delay Time		t _{d(OFF)}	-	63	-	
Fall Time		t _f	-	4.8	-	
Input Capacitance	V _{DS} =15V V _{GS} =0V f=1.0MHz	C _{iss}	-	3240	-	pF
Output Capacitance		C _{oss}	-	210	-	
Reverse Transfer Capacitance		C _{rss}	-	146	-	
Continuous Source Current ^{1,5}	V _G =V _D =0V , Force Current	I _s	-	-	47	A
Pulsed Source Current ^{2,5}		I _{SM}	-	-	100	A
Diode Forward Voltage ²	V _{GS} =0V , I _s =1A , T _J =25°C	V _{SD}	-	-	1.2	V
Reverse Recovery Time	I _F =15A , dI/dt=100A/μs , T _J =25°C	t _{rr}	-	18	-	ns
Reverse Recovery Charge		Q _{rr}	-	14	-	nC

Note :

- 1、The data tested by surface mounted on a 1 inch 2 FR-4 board with 2OZ copper.
- 2、The data tested by pulsed , pulse width ≤ 300us , duty cycle ≤ 2%
- 3、The EAS data shows Max. rating . The test condition is V DD =25V,VGS =10V,L=0.1mH,I AS =38A
- 4、The power dissipation is limited by 150°C junction temperature
- 5、The data is theoretically the same as I D and I DM , in real applications , should be limited by total power dissipation.

Ratings and Characteristic Curves

Typical Characteristics

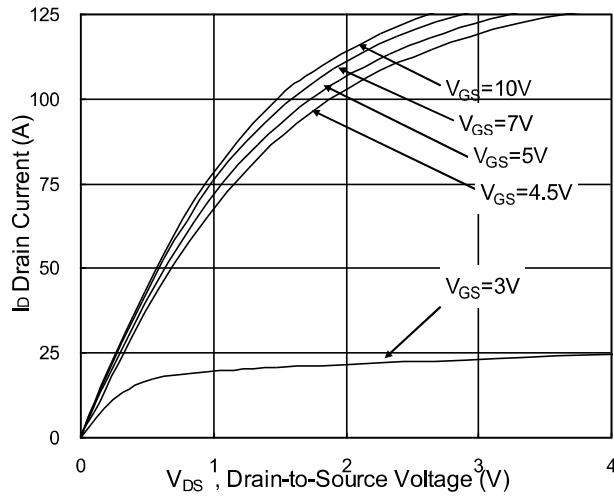


Fig.1 Typical Output Characteristics

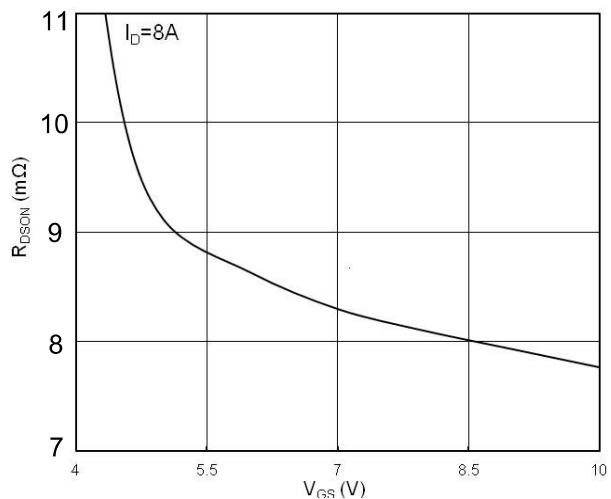


Fig.2 On-Resistance v.s Gate-Source

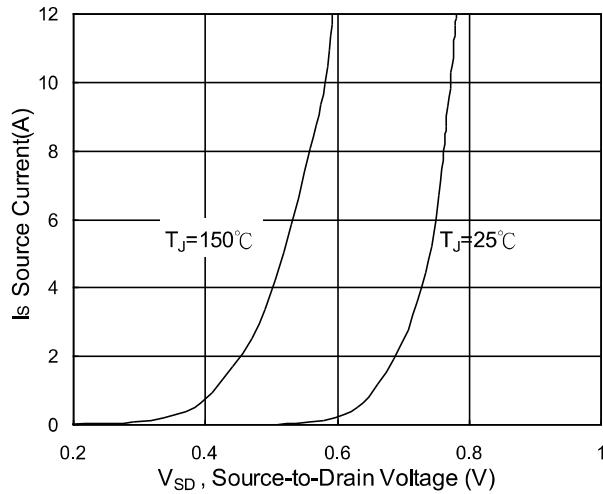


Fig.3 Forward Characteristics of Reverse

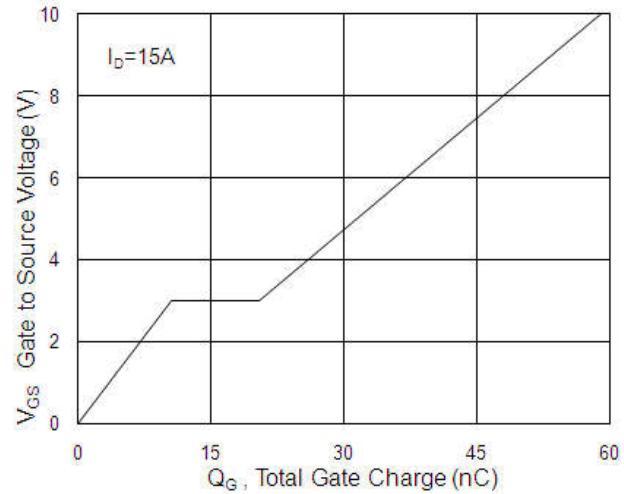


Fig.4 Gate-Charge Characteristics

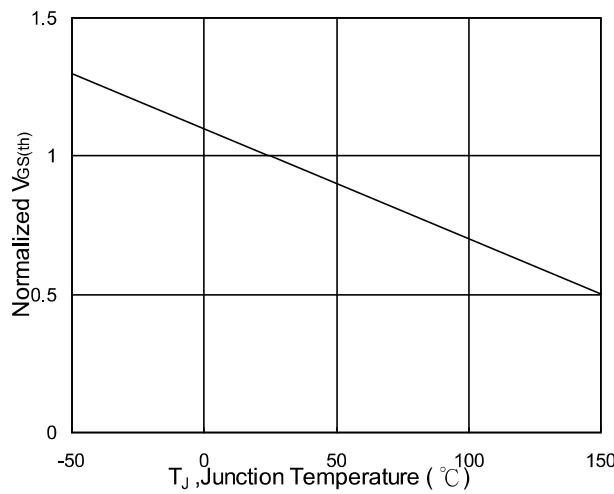


Fig.5 Normalized $V_{GS(th)}$ vs. T_J

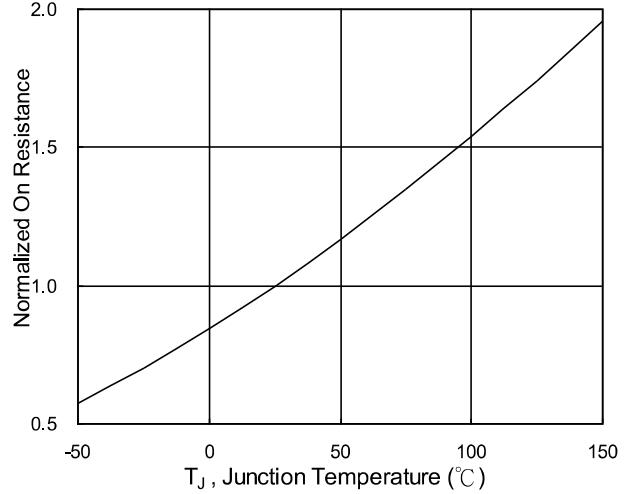


Fig.6 Normalized $R_{DS(on)}$ vs. T_J

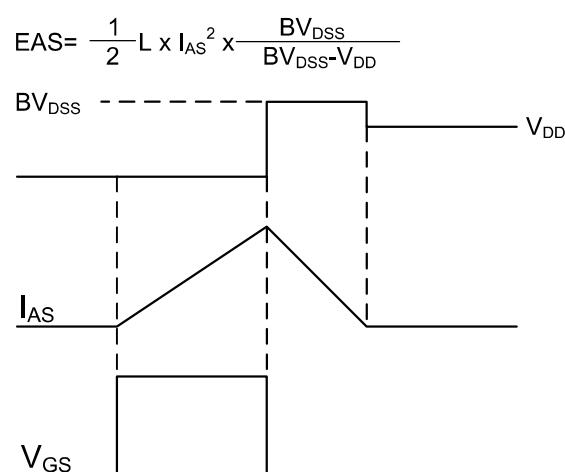
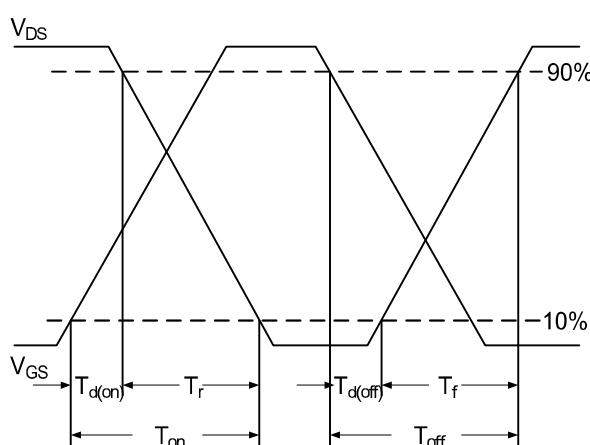
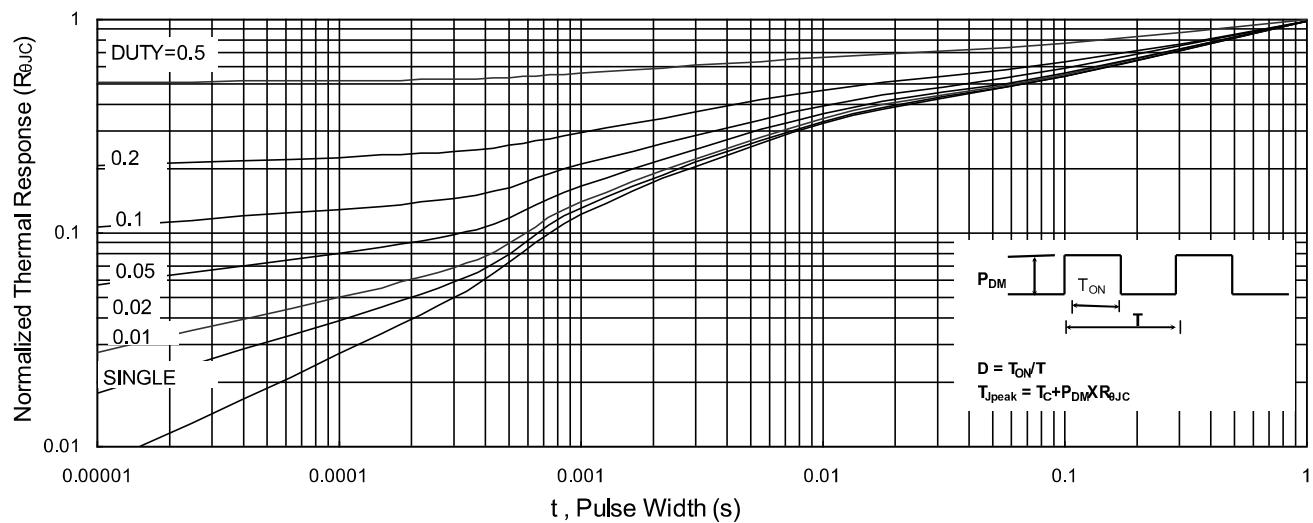
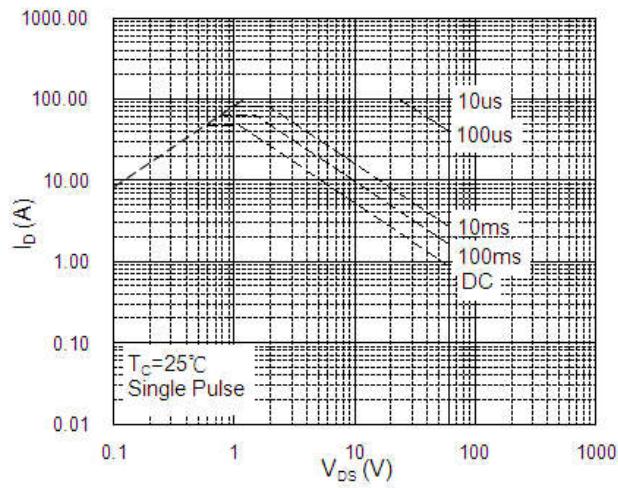
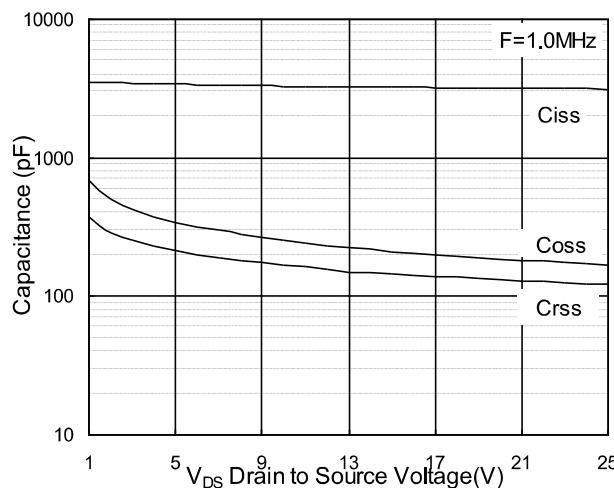
Ratings and Characteristic Curves


Fig.11 Unclamped Inductive Switching Waveform

Package Outline Dimensions Millimeters

TO-252

Dim.	Min.	Typ.	Max.
A	2.10	-	2.50
A2	0	-	0.10
B	0.66	-	0.86
B2	5.18	-	5.48
C	0.40	-	0.60
C2	0.44	-	0.58
D	5.90	-	6.30
D1	5.30REF		
E	6.40	-	6.80
E1	4.63	-	-
G	4.47	-	4.67
H	9.50	-	10.70
L	1.09	-	1.21
L2	1.35	-	1.65
V1	-	7°	-
V2	0°	-	6°

All Dimensions in millimeter